### Zibo Seno Electronic Engineering Co., Ltd.



## **EABS21 - EABS26**

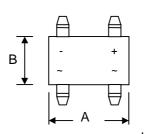


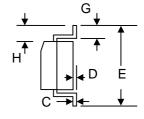


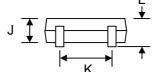
#### 2.0A SUPER FAST SURFACE MOUNT GLASS PASSIVATED BRIDGE RECTIFIER

#### **Features**

- Glass Passivated Die Construction
- Low Forward Voltage Drop
- High Current Capability
- High Surge Current Capability
- Designed for Surface Mount Application
- Plastic Material UL Flammability 94V-O







#### **Mechanical Data**

• Case: SOPA-4, ABS, Molded Plastic

 Terminals: Plated Leads Solderable per MIL-STD-202, Method 208

Polarity: As Marked on Case

Mounting Position: Any

Marking: Type Number

Lead Free: For RoHS / Lead Free Version

ABS						
Dim	Min	Max				
Α	4.80	5.30				
В	4.20	4.60				
С	0.15	0.25				
D	_	0.20				
Е	6.00	6.80				
G	0.30	0.70				
Н	0.90	1.10				
J	ı	1.50				
K	3.80	4.20				
L	1.22	1.72				
All Dimensions in mm						

#### Maximum Ratings and Electrical Characteristics @T<sub>A</sub>=25°C unless otherwise specified

Single Phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic	Symbol	EABS1	EABS2	EABS4	EABS6	Uni <sub>t</sub>
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	VRRM VRWM VR	100	200	400	600	V
RMS Reverse Voltage	VR(RMS)	70	140	280	560	V
Average Rectified Output Current (Note 1) $@T_A = 40^{\circ}C$ Average Rectified Output Current (Note 2) $@T_A = 40^{\circ}C$	lo	2.0				А
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	IFSM	60				А
I <sup>2</sup> t Rating for Fusing (t < 8.3ms)	l²t	5.0				A <sup>2</sup> s
Forward Voltage per element $@I_F = 2.0A$	VFM	0.95 1.25 1.7		1.7	V	
Peak Reverse Current $@T_A = 25^{\circ}C$ At Rated DC Blocking Voltage $@T_A = 125^{\circ}C$	IRM	5.0 500			μΑ	
Reverse Recovery Time (Note 4)	trr	35				nS
Typical Junction Capacitance per leg (Note 3)	Cj	13				pF
Typical Thermal Resistance per leg (Note 1)	R <sub>θ</sub> JA R <sub>θ</sub> JL	62.5 25				°C/W
Operating and Storage Temperature Range	Тj, Tsтg	-55 to +150				°C

Note: 1. Mounted on glass epoxy PC board with 1.3mm<sup>2</sup> solder pad.

- 2. Mounted on aluminum substrate PC board with 1.3mm<sup>2</sup> solder pad.
- 3. Measured at 1.0 MHz and applied reverse voltage of 4.0V D.C.
- 4. Measured with IF = 0.5A, IR = 1.0A, IRR = 0.25A. See figure 5.

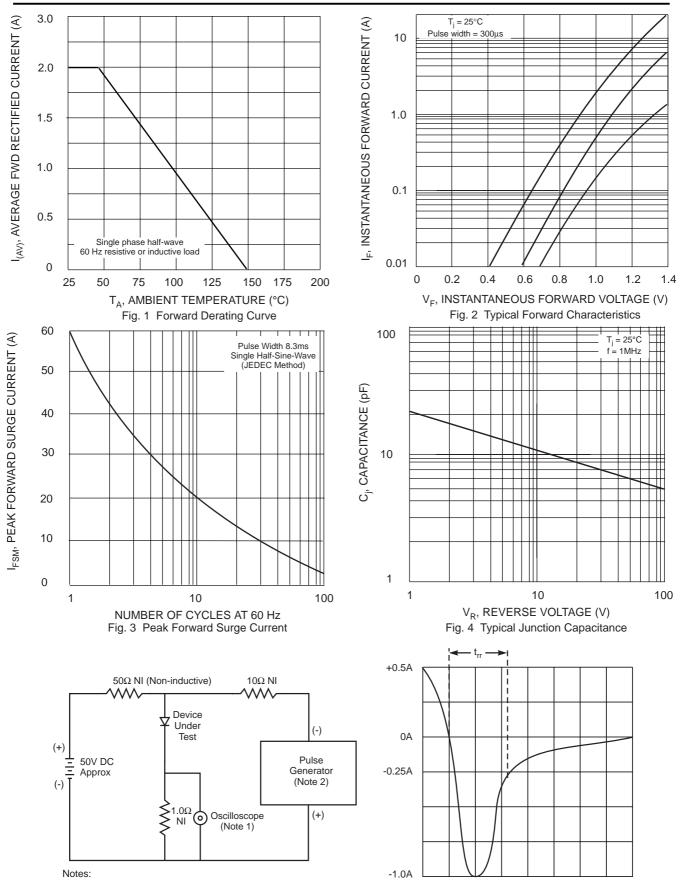
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5 Reverse Recovery Time Characteristic and Test Circuit

Set time base for 5/10ns/cm

1. Rise Time = 7.0ns max. Input Impedance =  $1.0M\Omega$ , 22pF.

2. Rise Time = 10ns max. Input Impedance =  $50\Omega$ .